

Internally Trimmed Precision IC Multiplier

FEATURES

Pretrimmed to $\pm 0.5\%$ Max 4-Quadrant Error All Inputs (X, Y and Z) Differential, High Impedance for $[(X_1-X_2)(Y_1-Y_2)/10] + Z_2$ Transfer Function Scale-Factor Adjustable to Provide up to X10 Gain Low Noise Design: 90 μ V rms, 10 Hz–10 kHz Low Cost, Monolithic Construction Excellent Long-Term Stability

APPLICATIONS

High Quality Analog Signal Processing Differential Ratio and Percentage Computations Algebraic and Trigonometric Function Synthesis Accurate Voltage Controlled Oscillators and Filters

PRODUCT DESCRIPTION

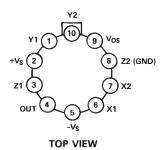
The AD632 is an internally-trimmed monolithic four-quadrant multiplier/divider. The AD632B has a maximum multiplying error of $\pm 0.5\%$ without external trims.

Excellent supply rejection, low temperature coefficients and long term stability of the on-chip thin film resistors and buried zener reference preserve accuracy even under adverse conditions. The simplicity and flexibility of use provide an attractive alternative approach to the solution of complex control functions.

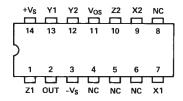
The AD632 is pin-for-pin compatible with the industry standard AD532 with improved specifications and a fully differential high impedance Z-input. The AD632 is capable of providing gains of up to X10, frequently eliminating the need for separate instrumentation amplifiers to precondition the inputs. The AD632 can be effectively employed as a variable gain differential input amplifier with high common-mode rejection. The effectiveness of the variable gain capability is enhanced by the inherent low noise of the AD632: 90 μ V rms.

AD632

PIN CONFIGURATIONS H-Package TO-100



D-Package SBDIP



TOP VIEW

PRODUCT HIGHLIGHTS

Guaranteed Performance Over Temperature

The AD632A and AD632B are specified for maximum multiplying errors of $\pm 1.0\%$ and $\pm 0.5\%$ of full scale, respectively at $+25^{\circ}$ C and are rated for operation from -25° C to $+85^{\circ}$ C. Maximum multiplying errors of $\pm 2.0\%$ (AD632S) and $\pm 1.0\%$ (AD632T) are guaranteed over the extended temperature range of -55° C to $+125^{\circ}$ C.

High Reliability

The AD632S and AD632T series are also available with MIL-STD-883 Level B screening and all devices are available in either the hermetically-sealed TO-100 metal can or **14-lead** ceramic DIP package.

Rev. B

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 One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A.

 Tel:
 781/329-4700

 Fax:
 781/461-3113

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$\label{eq:added} AD632 \mbox{--} SPECIFICATIONS \quad (@ +25^\circ \text{C}, \mbox{V}_s = \pm 15 \mbox{ V}, \mbox{ R} \geq 2 \mbox{ k} \Omega \mbox{ unless otherwise noted})$

Model	AD632A Min Typ Max	AD632B Min Typ Max	AD632S Min Typ Max	AD632T Min Typ Max	Units
MULTIPLIER PERFORMANCE					
Transfer Function	$\frac{(X_1 - X_2)(Y_1 - Y_2)}{10V} + Z_2$	$\frac{(X_1 - X_2)(Y_1 - Y_2)}{10W} + Z_2$	$\frac{(X_1 - X_2)(Y_1 - Y_2)}{10V} + Z_2$	$\frac{(X_1 - X_2)(Y_1 - Y_2)}{10V} + Z_2$	
Total Error ¹ ($-10 \text{ V} \le \text{X}, \text{Y} \le +10 \text{ V}$)	±1.0	±0.5	±1.0	±0.5	%
$T_A = Min \text{ to } Max$	±1.5	±1.0	±2.0	±1.0	%
Total Error vs. Temperature	±0.022	± 0.015	±0.02	±0.01	%/°C
Scale Factor Error					
$(SF = 10.000 \text{ V Nominal})^2$	±0.25	±0.1	±0.25	±0.1	%
Temperature-Coefficient of Scaling-Voltage	±0.02	±0.01	±0.2	±0.005	%/°C
Supply Rejection ($\pm 15 \text{ V} \pm 1 \text{ V}$)	±0.02 ±0.01	±0.01	±0.01	±0.01	%
Nonlinearity, X (X = 20 V p-p , Y = 10 V)	±0.4	±0.2 ±0.3	±0.4	±0.2 ±0.3	%
Nonlinearity, Y (Y = 20 V p-p, X = 10 V)	±0.2	$\pm 0.1 \ \pm 0.1$	±0.2	$\pm 0.1 \pm 0.1$	%
Feedthrough ³ , X (Y Nulled,	10.2		10.2	10.15.10.2	0/
X = 20 V p-p 50 Hz) Feedthrough ³ , Y (X Nulled,	±0.3	$\pm 0.15 \pm 0.3$	±0.3	$\pm 0.15 \pm 0.3$	%
Y = 20 V p-p 50 Hz)	±0.01	$\pm 0.01 \pm 0.1$	±0.01	±0.01 ±0.1	%
Output Offset Voltage	$\pm 5 \pm 30$	± 2 ± 15	$\pm 5 \pm 30$	$\pm 2 \pm 15$	mV
Output Offset Voltage Drift	200	100	500	300	µV/°C
DYNAMICS					
Small Signal BW, ($V_{OUT} = 0.1 \text{ rms}$)	1	1	1	1	MHz
1% Amplitude Error (C_{LOAD} = 1000 pF)	50	50	50	50	kHz
Slew Rate (V _{OUT} 20 p-p)	20	20	20	20	V/µs
Settling Time (to 1%, $\Delta V_{OUT} = 20 \text{ V}$)	2	2	2	2	μs
NOISE					
Noise Spectral-Density $SF = 10 V$	0.8	0.8	0.8	0.8	$\mu V/\sqrt{Hz}$
$SF = 3 V^4$ Wideband Noise A = 10 Hz to 5 MHz	0.4	0.4	0.4	0.4	$\mu V/\sqrt{Hz}$ mV rms
P = 10 Hz to 10 kHz	90	90	90	90	$\mu V/rms$
OUTPUT					
Output Voltage Swing	±11	±11	±11	±11	V
Output Impedance ($f \le 1 \text{ kHz}$)	0.1	0.1	0.1	0.1	Ω
Output Short Circuit Current					
$(R_L = 0, T_A = Min \text{ to } Max)$	30	30	30	30	mA
Amplifier Open Loop Gain (f = 50 Hz)	70	70	70	70	dB
INPUT AMPLIFIERS $(X, Y \text{ and } Z)^5$					
Signal Voltage Range (Diff. or CM Operating Diff.)	± 10	± 10	± 10 ± 12	± 10 ± 12	V V
Offset Voltage X, Y	$\pm 12 \pm 5 \pm 20$	$ \pm 12 \\ \pm 2 \pm 10 $	$\pm 12 \pm 5 \pm 20$	$\pm 12 \pm 2 \pm 10$	w mV
Offset Voltage Drift X, Y	100	50	100	150	μV/°C
Offset Voltage Z	±5 ±30	±2 ±15	±5 ±30	±2 ±15	mV
Offset Voltage Drift Z	200	100	500	300	µV/°C
CMRR	60 80	70 90	60 80	70 90	dB
Bias Current Offset Current	0.8 2.0	0.8 2.0 0. I	0.8 2.0	0.8 2.0 0.1	μΑ
Differential Resistance	0.1	10	0.1	10	μΑ ΜΩ
	10	10	10		
DIVIDER PERFORMANCE Transfer Function $(X_1 > X_2)$	$10V \frac{(Z_2 - Z_1)}{(X_1 - X_2)} + Y_1$	$10V \frac{(Z_2 - Z_1)}{(X_1 - X_2)} + Y_1$	$10V \frac{(Z_2 - Z_1)}{(X_1 - X_2)} + Y_1$	$10V \frac{(Z_2 - Z_1)}{(X_1 - X_2)} + Y_1$	
Total Error ¹	$(X_1 - X_2)$	$(X_1 - X_2)^{-1}$	$(X_1 - X_2)^{-1}$	$(X_1 - X_2)^{+1}$	
$(X = 10 V, -10 V \le Z \le +10 V)$	±0.75	±0.35	±0.75	±0.35	%
$(X = 1 V, -1 V \le Z \le +1 V)$	±2.0	± 1.0	±2.0	±1.0	%
$(0.1 \text{ V} \le \text{X} \le 10 \text{ V}, -10 \text{ V} \le \text{Z} \le 10 \text{ V})$	±2.5	± 1.0	±2.5	±1.0	%
SQUARER PERFORMANCE	(V V) ²	(¥ ¥ 2	(¥ ¥ 2	(W W) ²	
Transfer Function	$\frac{(X_1 - X_2)^2}{10V} + Z_2$	$\frac{(X_1 - X_2)^2}{10V} + Z_2$ ±0.3	$\frac{(X_1 - X_2)^2}{10V} + Z_2$	$\frac{\frac{(X_1 - X_2)^2}{10V} + Z_2}{\pm 0.3}$	
Total Error ($-10 \text{ V} \le \text{X} \le 10 \text{ V}$)	±0.6	±0.3	±0.6	±0.3	%
SQUARE-ROOTER PERFORMANCE					
Transfer Function, $(Z_1 \leq Z_2)$	$\sqrt{10 V(Z_2 - Z_1) + X_2}$	$\sqrt{10V(Z_2 - Z_1) + X_2}$	$\sqrt{10 V(Z_2 - Z_1) + X_2}$	$\sqrt{10 V(Z_2 - Z_1) + X_2}$	
Total Error ¹ (1 V \leq Z \leq 10 V)	±1.0	±0.5	±1.0	±0.5	%

		AD632	A		AD632	в		AD632	S		AD63	2 T	
Model	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Units
POWER SUPPLY SPECIFICATIONS													
Supply Voltage													
Rated Performance		±15			±15			±15			±15		V
Operating	±8		±18	±8		±18	±8		±22	±8		±22	V
Supply Current													
Quiescent		4	6		4	6		4	6		4	6	mA

NOTES

¹Figures given are percent of full-scale, ± 10 V (i.e., 0.01% = 1 mV).

 ^2May be reduced to 3 V using external resistor between $-\text{V}_\text{S}$ and SF.

³Irreducible component due to nonlinearity: excludes effect of offsets.

⁴Using external resistor adjusted to give SF = 3 V.

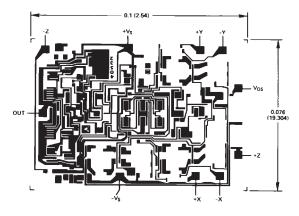
⁵See functional block diagram for definition of sections.

All min and max specifications are guaranteed.

Specifications shown in **boldface** are tested on all production units at final electrical test. Results from those tests are used to calculate outgoing quality levels. Specifications subject to change without notice.

CHIP DIMENSIONS AND PAD LAYOUT

Dimensions shown in inches and (mm). (Contact factory for latest dimensions.)



For further information, consult factory.

Thermal Characteristics

Thermal Resistance	$\theta_{\rm JC}$ = 25°C/W for H-10
	$\theta_{IA} = 150^{\circ}C/W$ for H-10
	$\theta_{\rm JC}$ = 25°C/W for D-14
	$\theta_{JA} = 95^{\circ}C/W$ for D-14

AD632

Typical Performance Curves

(typical @ +25°C with $\pm V_S = 15 \text{ V}$)

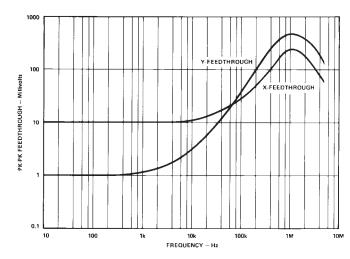


Figure 1. AC Feedthrough vs. Frequency

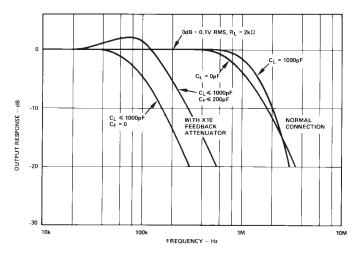


Figure 2. Frequency Response as a Multiplier

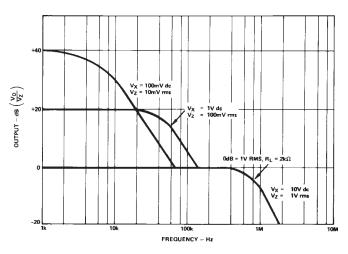


Figure 3. Frequency Response vs. Divider Denominator Input Voltage

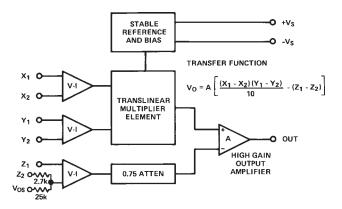


Figure 4. AD632 Functional Block Diagram

OPERATION AS A MULTIPLIER

Figure 5 shows the basic connection for multiplication. Note that the circuit will meet all specifications without trimming.

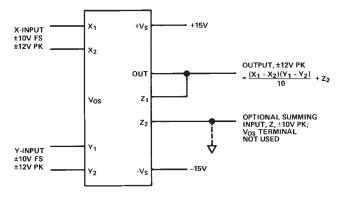


Figure 5. Basic Multiplier Connection

In some cases the user may wish to reduce ac feedthrough to a minimum (as in a suppressed carrier modulator) by applying an external trim voltage (± 30 mV range required) to the X or Y input. Curve 1 shows the typical ac feedthrough with this adjustment mode. Note that the feedthrough of the Y input is a factor of 10 lower than that of the X input and should be used in applications where null suppression is critical.

The Z_2 terminal of the AD632 may be used to sum an additional signal into the output. In this mode the output amplifier behaves as a voltage follower with a 1 MHz small signal bandwidth and a 20 V/µs slew rate. This terminal should always be referenced to the ground point of the driven system, particularly if this is remote. Likewise the differential inputs should be referenced to their respective signal common potentials to realize the full accuracy of the AD632.

A much lower scaling voltage can be achieved without any reduction of input signal range using a feedback attenuator as shown in Figure 6. In this example, the scale is such that $V_{OUT} = XY$, so that the circuit can exhibit a maximum gain of 10. This connection results in a reduction of bandwidth to about 80 kHz without the peaking capacitor C_F . In addition, the output offset voltage is increased by a factor of 10 making external adjustments necessary in some applications.

Feedback attenuation also retains the capability for adding a signal to the output. Signals may be applied to the Z terminal, where they are amplified by -10, or to the common ground connection where they are amplified by -1. Input signals may also be applied to the lower end of the 2.7 k Ω resistor, giving a gain of +9.

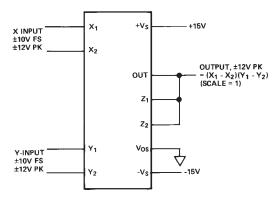


Figure 6. Connections for Scale-Factor of Unity

OPERATION AS A DIVIDER

Figure 7 shows the connection required for division. Unlike earlier products, the AD632 provides differential operation on both numerator and denominator, allowing the ratio of two floating variables to be generated. Further flexibility results from access to a high impedance summing input to Y_1 . As with all dividers based on the use of a multiplier in a feedback loop, the bandwidth is proportional to the denominator magnitude, as shown in Figure 3.

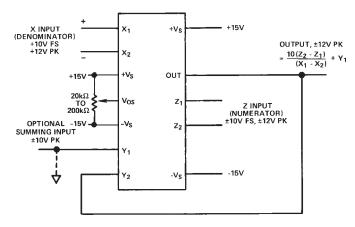


Figure 7. Basic Divider Connection

Without additional trimming, the accuracy of the AD632B is sufficient to maintain a 1% error over a 10 V to 1 V denominator range (The AD535 is functionally equivalent to the AD632 and has guaranteed performance in the divider and square-rooter configurations and is recommended for such applications).

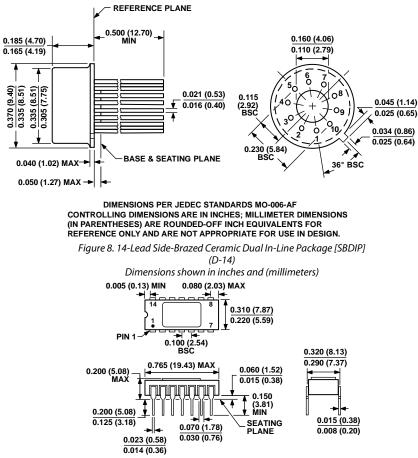
This range may be extended to 100:1 by simply reducing the X offset with an externally generated trim voltage (range required is ± 3.5 mV max) applied to the unused X input. To trim, apply a ramp of +100 mV to +V at 100 Hz to both X₁ and Z₁ (if X₂ is used for offset adjustment, otherwise reverse the signal polarity) and adjust the trim voltage to minimize the variation in the output.*

Since the output will be near +10 V, it should be ac-coupled for this adjustment. The increase in noise level and reduction in bandwidth preclude operation much beyond a ratio of 100 to 1.

*See the AD535 data sheet for more details.

AD632

OUTLINE DIMENSIONS



022306-A

CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

> Figure 9. 10-Pin Metal Header Package [TO-100] (H-10)

Dimensions shown in inches and (millimeters)

ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option
AD632AD	-25°C to +85°C	14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP]	D-14
AD632ADZ	-25°C to +85°C	14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP]	D-14
AD632AH	-25°C to +85°C	10-Pin Metal Header Package [TO-100]	H-10
AD632AHZ	-25°C to +85°C	10-Pin Metal Header Package [TO-100]	H-10
AD632BD	–25°C to +85°C	14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP]	D-14
AD632BDZ	-25°C to +85°C	14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP]	D-14
AD632BH	–25°C to +85°C	10-Pin Metal Header Package [TO-100]	H-10
AD632BHZ	-25°C to +85°C	10-Pin Metal Header Package [TO-100]	H-10
AD632SD	-55°C to +125°C	14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP]	D-14
AD632SH	–55°C to +125°C	10-Pin Metal Header Package [TO-100]	H-10
AD632SH/883B	-55°C to +125°C	10-Pin Metal Header Package [TO-100]	H-10
AD632TD	–55°C to +125°C	14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP]	D-14
AD632TD/883B	–55°C to +125°C	14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP]	D-14
AD632TH	–55°C to +125°C	10-Pin Metal Header Package [TO-100]	H-10
AD632TH/883B	–55°C to +125°C	10-Pin Metal Header Package [TO-100]	H-10

¹ Z = RoHS Compliant Part.

REVISION HISTORY

Changes to Pin Configurations and Product Highlights	
Section	1
Changes to Thermal Characteristics Section	3
Updated Outline Dimensions	6
Changes to Ordering Guide	6

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